BLP10H605

Broadband LDMOS driver transistor

Rev. 4 — 1 September 2015



1. Product profile

1.1 General description

A 5 W plastic LDMOS power transistor for broadcast transmitter and ISM applications at frequencies from HF to 1400 MHz.

Table 1. Application performance

Test signal	f	V _{DS}	P_L	Gp	η _D
	(MHz)	(V)	(W)	(dB)	(%)
CW	860	50	5	22.4	59.6

1.2 Features and benefits

- Easy power control
- Integrated dual side ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 1400 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

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2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1, 3, 4, 6, 7, 9, 10, 12	n.c.		
2	gate1	1 12	11
5	gate2	2 11 3 10	, F
8	drain2	4 9	13
11	drain1	5	5—
13	source [1]		<u>'</u>
		Transparent top view	8 aaa-010780

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package	Package			
	Name	Description	Version		
BLP10H605	HVSON12	plastic thermal enhanced very thin small outline package; no leads; 12 terminals; body $5\times6\times0.85$ mm	SOT1352-1		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	104	V
V_{GS}	gate-source voltage		-6	+11	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

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5. Recommended operating conditions

See application note AN11520 for more details.

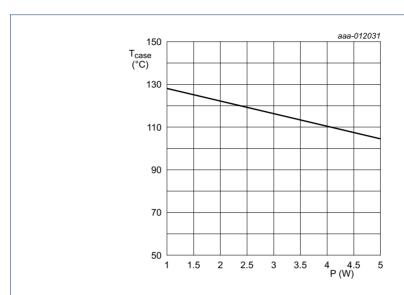


Fig 1. Recommended operating area; case temperature as a function of power dissipation

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 5 W	<u>[1]</u> 5.5	K/W

^[1] $R_{th(j-c)}$ is measured under RF conditions

7. Characteristics

Table 6. DC characteristics

 $T_j = 25$ °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.06 \text{ mA}$	104	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 6 mA	1.25	1.7	2.25	V
V_{GSq}	gate-source quiescent voltage	V _{DS} = 50 V; I _D = 30 mA	1.35	1.78	2.25	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	0.95	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 210 \text{ mA}$	-	4580	-	mΩ

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Table 7. AC characteristics

 $T_i = 25$ °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{rs}	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	0.07	-	pF
C _{iss}	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 0 \text{ V}; f = 1 \text{ MHz}$	-	6.8	-	pF
Coss	output capacitance	V _{GS} = 0 V; V _{DS} = 50 V; f = 1 MHz	-	2.24	-	pF

Table 8. RF characteristics

Test signal: CW pulsed; $t_p = 50~\mu s$; $\delta = 10~\%$; f = 860~MHz; RF performance at $V_{DS} = 50~V$; $I_{Dq} = 30~mA$; $T_{case} = 25~^{\circ}C$; unless otherwise specified, in a class-AB production test circuit [1].

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 5 W	20.2	22.4	27.4	dB
η_{D}	drain efficiency	P _L = 5 W	57	59.6	-	%

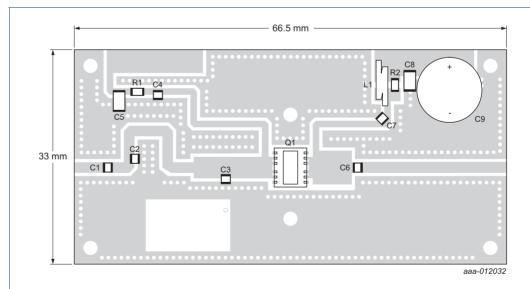
^[1] The industrial test method is performed on special hardware to accommodate the requirements of production. The test results in this table are correlated to correspond with a performance in the application.

8. Test information

8.1 Ruggedness in class-AB operation

The BLP10H605 is capable of withstanding a load mismatch corresponding to VSWR = 35 : 1 through all phases under the following conditions: V_{DS} = 50 V; I_{Dq} = 30 mA; P_{L} = 5 W; f = 860 MHz.

8.2 Test circuit



Printed-Circuit Board (PCB): Rogers RO4350; ϵ_{r} = 3.48; height = 0.762 mm; thickness copper plating = 35 μ m.

See Table 9 for a list of components.

Fig 2. Component layout

Table 9. List of components See Figure 2 for component layout.

Component	Description	Value	Remarks
C1, C4, C7	multilayer ceramic chip capacitor	100 pF [1]	
C2	multilayer ceramic chip capacitor	8.2 pF [1]	
C3	multilayer ceramic chip capacitor	5.1 pF [1]	
C5	multilayer ceramic chip capacitor	1 μF, 25 V	Murata GRM31MR71E105KA01L
C6	multilayer ceramic chip capacitor	2.2 pF [1]	
C8	multilayer ceramic chip capacitor	1 μF, 50 V	Murata GRM32RR71H105KA01L
C9	electrolytic capacitor	220 μF, 63 V	
L1	wire inductor, 0.8 mm copper wire	2 turn, D = 3 mm	
R1	resistor	0 Ω	SMD 0805
R2	resistor	10 Ω	SMD 0805
Q1	transistor	-	BLP10H605

^[1] American Technical Ceramics type 100A or capacitor of same quality.

8.3 Graphical data

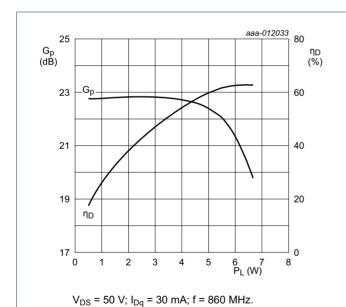
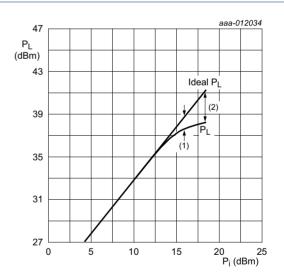


Fig 3. Power gain and drain efficiency as function of output power; typical values

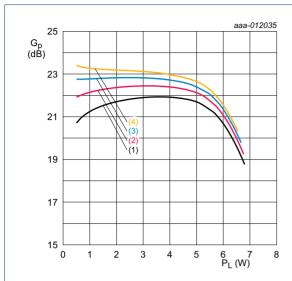


 $V_{DS} = 50 \text{ V}; I_{Dq} = 30 \text{ mA}; f = 860 \text{ MHz}.$

- (1) $P_{L(1dB)} = 37.55 \text{ dBm } (5.7 \text{ W})$
- (2) $P_{L(3dB)} = 38.24 \text{ dBm } (6.7 \text{ W})$

Fig 4. Output power as a function of input power; typical values

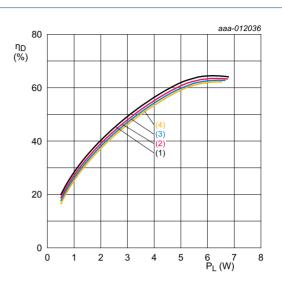
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V_{DS} = 50 V; f = 860 MHz.

- (1) $I_{Dq} = 10 \text{ mA}$
- (2) $I_{Dq} = 20 \text{ mA}$
- (3) $I_{Dq} = 30 \text{ mA}$
- (4) $I_{Dq} = 40 \text{ mA}$

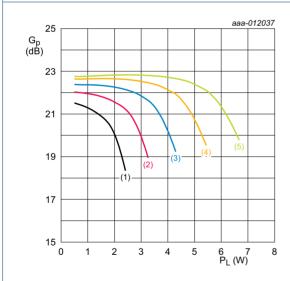
Fig 5. Power gain as a function of output power; typical values



 $V_{DS} = 50 \text{ V}; f = 860 \text{ MHz}.$

- (1) $I_{Dq} = 10 \text{ mA}$
- (2) $I_{Dq} = 20 \text{ mA}$
- (3) $I_{Dq} = 30 \text{ mA}$
- (4) $I_{Dq} = 40 \text{ mA}$

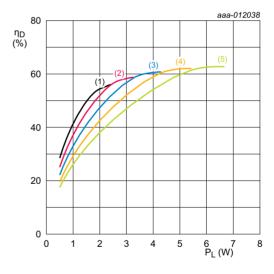
Fig 6. Drain efficiency as a function of output power; typical values



 $I_{Dq} = 30 \text{ mA}$; f = 860 MHz.

- (1) $V_{DS} = 30 \text{ V}$
- (2) $V_{DS} = 35 V$
- (3) $V_{DS} = 40 \text{ V}$
- (4) $V_{DS} = 45 \text{ V}$
- (5) $V_{DS} = 50 \text{ V}$

Fig 7. Power gain as a function of output power; typical values



 $I_{Dq} = 30 \text{ mA}$; f = 860 MHz.

- (1) $V_{DS} = 30 \text{ V}$
- (2) $V_{DS} = 35 V$
- (3) $V_{DS} = 40 \text{ V}$
- (4) $V_{DS} = 45 \text{ V}$
- (5) $V_{DS} = 50 \text{ V}$

Fig 8. Drain efficiency as a function of output power; typical values

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9. Package outline

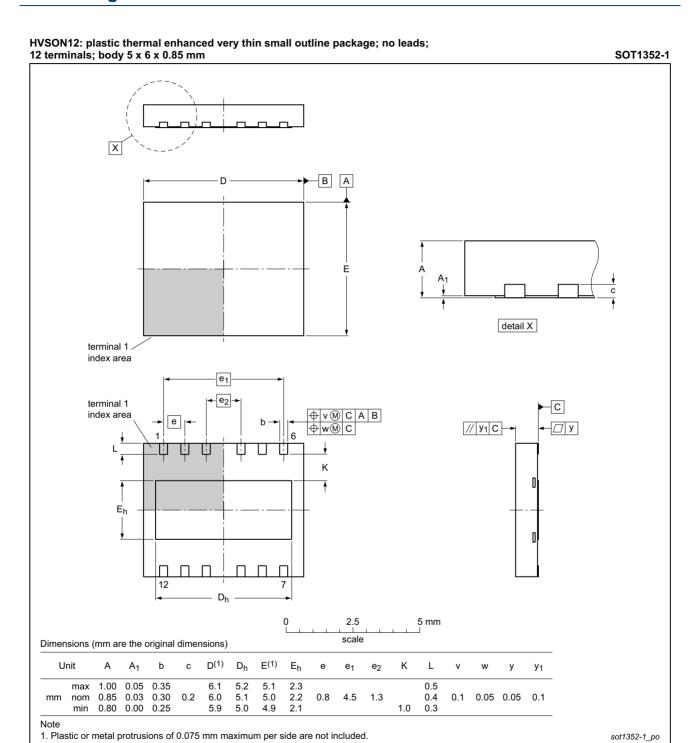


Fig 9. Package outline SOT1352-1 (HVSON12)

IEC

projection

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Issue date

13-03-26

13-07-16

JEITA

References

JEDEC

MO-229

version

SOT1352-1

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10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

11. Abbreviations

Table 10. Abbreviations

Acronym	Description	
CW	Continuous Wave	
ESD	ElectroStatic Discharge	
LDMOS	Laterally Diffused Metal-Oxide Semiconductor	
HF	High Frequency	
ISM	Industrial, Scientific and Medical	
SMD	Surface Mounted Device	
VSWR	Voltage Standing-Wave Ratio	

12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLP10H605 v.4	20150901	Product data sheet		BLP10H605 v.3	
Modifications:	The format of Ampleon.	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 			
	 Legal texts h 	nave been adapted to the new co	ompany name where a	ppropriate.	
BLP10H605 v.3	20141002	Product data sheet	-	BLP10H605 v.2	
BLP10H605 v.2	20140418	Objective data sheet	-	BLP10H605 v.1	
BLP10H605 v.1	20140221	Objective data sheet	-	-	

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13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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